# Magnetic, Surface And Elemental Characterization of FECO (50:50, 70:30) 50nm Thin Film Grown By Ultra High Vacuum DC Magnetron Sputtering on Silicon (001) Substrate

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**Abstract.** Fe<sub>50</sub>Co<sub>50</sub> and Fe<sub>70</sub>Co<sub>30</sub>(50nm) thin films prepared onto the Silicon (001) substrate at room temperature using UHV DC Magnetron Sputtering (PVD) system. We prepared FeCofilms and characterized their Magnetic, Topographic, Morphology and Elemental analysis using VSM, AFM, FESEM, and EDAX technique respectively. VSM result confirmed both materials are good magnetic in nature and both their Coercivity nearly 2000e but Fe<sub>50</sub>Co<sub>50</sub>has higher magnetization when compared to Fe<sub>70</sub>Co<sub>30</sub> film. From AFM results, the average roughness and root mean Square of Fe<sub>50</sub>Co<sub>50</sub> film value are double the times higher than Fe<sub>70</sub>Co<sub>30</sub> film. From FESEM result Morphology of the Fe<sub>50</sub>Co<sub>50</sub>film like a columnar structure and Fe<sub>70</sub>Co<sub>30</sub> as like columnar agglomeration structure. EDAX result revels high number of oxygen content present in Fe<sub>70</sub>Co<sub>30</sub> film than Fe<sub>50</sub>Co<sub>50</sub> film as well as no other impurities present in the film.

Keywords: Magnetic thin film, FeCo, VSM, Spin polarization.

#### **1** Introduction

A FeCo magnetic properties such as Coercivity, Magnetization, Retentivity depends on ratio of Fe and Co content[1]. FeCoalloy various ratios reported as65:35, 70:30, 50:50 and these magnetic thin film frequently used in magnetic sensors, Actuators, Magnetic recordings MRAM applications [2]. Past two decades spintronic communities also very interest inFeCo based thin film for Spin-valve (Spin injector) application[3, 4]. FeCo thin film used as the spin injector and spin detector in MTJ and GMR devices. Due to material magnetic property (Ferro-Magnet), 50% of Spin Polarization and High Curie TemperatureTc-790K which is very higher than the room temperature level.Fe<sub>70</sub>Co<sub>30</sub> (100nm) film has low coercivity, recorded when500° C substrate temperature applied. The different morphology changedwhen substrate temperature changes.Fe<sub>50</sub>Co<sub>50</sub> thin film applied to post annealing leads to change in magneticproperties. [5,6].FeCo spin injector based spin valve devices was fabricated. Bottom electrode Fe<sub>50</sub>Co<sub>50</sub> (40nm) was selected as a spin injector withwork function (4.9eV) which was close to the organic semiconductor homo level[7]. T. Moriyama et al prepared MTJs device with FeCo as the spin injector and detector [8]. In this paper we discussed about the FeCo (Fe<sub>50</sub>Co<sub>50</sub>, Fe<sub>70</sub>Co<sub>30</sub>) 50nm thin film Prepared onto the Si (001) substrate using UHV DC

Magnetron Sputtering and characterized their Magnetic, Elemental, 3D-Topography and Morphology of the film studied using experimentally.

### **Experimental Work**

Initially, the Silicon substrate cut into  $1x1 \text{ cm}^2$  using a glass cutter then, immersed in ultra-sonicated Acetone, IPA and Double distilled water for removing small particles on top of the substrate surface. This cleaned Si substrate loaded into the ultra-high vacuum chamber. The UHV DC Magnetron sputtering power was fixed to 30W and Argon gas flow was maintained at 7Sccm. The base pressure and deposition pressure were  $3x10^{-7}$ torr and 4mtorr, respectively. The distance between the substrate and the target was 10cm, Silicon Substrate was rotated at 10rpm as well as pre-sputtered for 10mins. The Fe<sub>50</sub>Co<sub>50</sub> (50nm) was deposited on a Si substrate. The thickness of the film already optimized as well as confirmed in the quartz crystal thickness monitor. Prepared FeCo thin film sample kept one day in high vacuum (base vacuum). The same conditions are maintained for Fe<sub>70</sub>Co<sub>30</sub>. Estimated thickness of the films was studied in VSManalysis using GMW based magnet system (GMW 3473-70). Two-dimensional Morphology and elemental analysis were studied using FESEM-EDAX measurements (ZESIS instrument).3-Dimensional Topographic of the FeCo film was studied by Atomic Force Microscopy by park systems, NX20 using tapping mode operation.

#### **Result And Discussion**





Fig 1. Fe<sub>50</sub>Co<sub>50</sub>film thickness from stylus profilometer



Fig 2. Fe<sub>70</sub>Co<sub>30</sub>film thickness from stylus profilometer

Figure 3&4show that EDAX result of Sputtered  $Fe_{70}Co_{30}$  and  $Fe_{50}Co_{50}$ thin films which contains Fe, Co elements (sputtered elements). We confirm oxygen present in  $Fe_{70}Co_{30}$  it may react with sample surface. Silicon peak indicates that it was a substrate material. Result also confirms no other element present in the prepared thin films.  $Fe_{70}Co_{30}$  EDAX result (fig 3) also clearly indicated high number of oxygen content which may confirms that it can easily react with oxygen and might be the reason for the stability.



Fig 3.Fe70Co30elemental analysis from EDAX result



Fig 4. Fe<sub>50</sub>Co<sub>50</sub>elemental analysis from EDAX result

FeCo thin film morphology was studied by using the FE-SEM technique. Morphology of the FeCo (50:50, 70:30) Film like columnar structure while  $Fe_{70}Co_{30}$  columnar agglomeration takes place due to it may easily react with oxygen shown in fig 5.From EDS result its evident of high content of oxygen presence in the  $Fe_{70}Co_{30}$  film. Both the FeCo film morphology focusing on 100nm range and 150Kx magnification. The images confirmed  $Fe_{50}Co_{50}$  40nm film more uniform than  $Fe_{70}Co_{30}$  40nm film.



Fig 5. FESEM image of FeCo 40nm thickness . a)  $Fe_{50}Co_{50}$  and b)  $Fe_{70}Co_{30}$ 

From 3D topographical result, average roughness (Ra) and root mean square (Rq) was studied by AFM technique shown in fig 6. Scanning area was done by 5x5 micrometer. The

average roughness of  $Fe_{50}Co_{50}and\ Fe_{70}Co_{30}$  film as 1.86nm and 0.68nm respectively. Root mean square value as 1.98 and 0.82 nm respectively.  $Fe_{50}Co_{50}$  film roughness and root mean square double the time higher the  $Fe_{70}Co_{30}$  film roughness.

	Average	Root	mean			
FeCo	Roughness (Ra)	Square	(Rq)	Coercivity	Retentivity	Magnetization
	nm	nm	_	Hc (Oe)	Mr (emu/cc)	Ms (emu/cc)
Fe <sub>50</sub> Co <sub>50</sub>	1.841	1.968		214	143	159
Fe <sub>70</sub> Co <sub>30</sub>	0.645	0.816		206	185	202

Table 1: FeCo magnetic and Surface properties





FeCo thin film magnetic properties were studied by VSM analysis shown inFig 7.Magnetic properties such as coercivity, saturation, andretentivity were studied using hysteresis loop. Result confirmsFe<sub>70</sub>Co<sub>30</sub> and Fe<sub>50</sub>Co<sub>50</sub>have magneticin nature confirmed by hysteresis loop. Fe<sub>50</sub>Co<sub>50</sub> and Fe<sub>70</sub>Co<sub>30</sub>Coercivity nearly same as 214Oe and 206Oe, respectively.Magnetization and Magnetic saturation higher for Fe<sub>50</sub>Co<sub>50</sub>than Fe<sub>70</sub>Co<sub>30</sub>. Both FeCo look like they have the same hysteresis loop.



Fig 7. Magnetic Hysteresis graph of FeCo 40nm thickness .a)  $Fe_{50}Co_{50}$  (black) and b)  $Fe_{70}Co_{30}$  (Red)

## Conclusion

FeCowith two different ratios (50:50, 70:30) thin filmswere prepared using by UHV DC Magnetron Sputtering. Elemental analysis confirms no other element present in  $Fe_{50}Co_{50}$  while oxygen content presents in  $Fe_{70}Co_{30}$  it may easily react with atmospheric condition. Morphology of the film looks like similar structure. Surface roughness of the film higher for  $Fe_{50}Co_{50}$  film and corresponding magnetization also varied. From above results it concludes,  $Fe_{50}Co_{50}$  is a suitable electrode than  $Fe_{70}Co_{30}$  for magnetic sensor application

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